ON Semiconductor

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MOSFET – Power, P-Channel, SOT-23

-20 V, -1.3 A

These miniature surface mount MOSFETs low $R_{DS(on)}$ assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are DC–DC converters and power management in portable and battery–powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

Features

- Low R_{DS(on)} Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- NVTR Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- Pb-Free and Halide-Free Packages are Available

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	-20	V
Gate-to-Source Voltage - Continuous	V _{GS}	±12	V
Drain Current – Continuous @ T _A = 25°C – Pulsed Drain Current (t _p ≤ 10 μs)	I _D I _{DM}	-1.3 -4.0	A A
Total Power Dissipation @ $T_A = 25^{\circ}C$	PD	400	mW
Operating and Storage Temperature Range	T _J , T _{stg}	– 55 to 150	°C
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	300	°C/W
Maximum Lead Temperature for Soldering Purposes, (1/8" from case for 10 s)	ΤL	260	°C

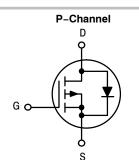
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

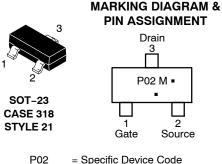


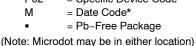
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V _{(BR)DSS}	R _{DS(on)} Max	I _D Max
–20 V	220 mΩ @ -4.5 V	–1.3 A







*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

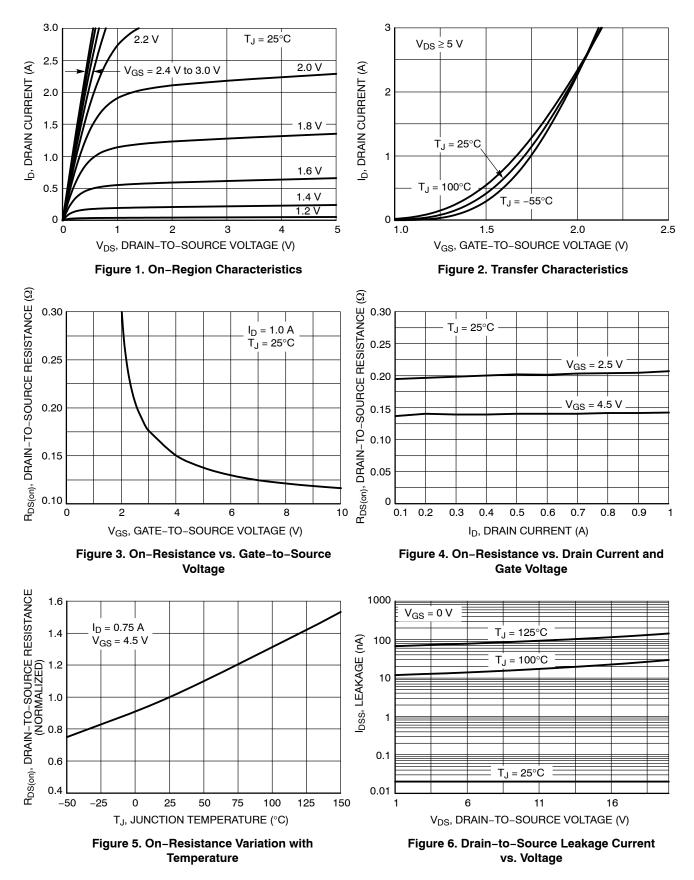
Device	Package	Shipping [†]		
NTR1P02LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel		
NTR1P02LT3G	SOT-23 (Pb-Free)	10,000 Tape & Reel		
NVTR01P02LT1G	SOT-23 (Pb-Free)	3000 Tape & Reel		

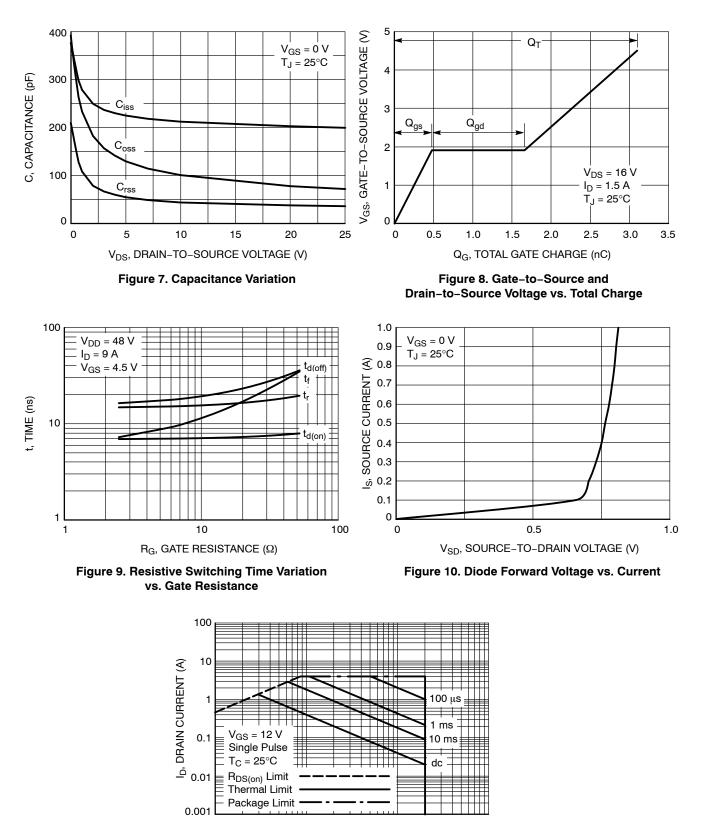
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

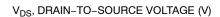
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Parameter	Test Condition	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•				
Drain-to-Source Breakdown Volt- age	$(V_{GS} = 0 \text{ V}, \text{ I}_{D} = -10 \mu\text{A})$	V _{(BR)DSS}	-20			V
Zero Gate Voltage Drain Current		I _{DSS}			-1.0 -10	μΑ
Gate-Body Leakage Current	(V _{GS} = \pm 12 V, V _{DS} = 0 V)	I _{GSS}			±100	nA
ON CHARACTERISTICS (Note 1)						
Gate Threshold Voltage	($V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$)	V _{GS(th)}	-0.7	-1.0	-1.25	V
Static Drain-to-Source On-Resistance	$(V_{GS} = -4.5 \text{ V}, I_D = -0.75 \text{ A})$ $(V_{GS} = -2.5 \text{ V}, I_D = -0.5 \text{ A})$	r _{DS(on)}		0.140 0.200	0.22 0.35	Ω
DYNAMIC CHARACTERISTICS						
Input Capacitance	(V _{DS} = -5.0 V)	C _{iss}		225		pF
Output Capacitance	(V _{DS} = -5.0 V)	C _{oss}		130		1
Transfer Capacitance	(V _{DS} = -5.0 V)	C _{rss}		55		
SWITCHING CHARACTERISTICS (Note 2)					
Turn-On Delay Time		t _{d(on)}		7.0		ns
Rise Time	$(V_{GS} = -4.5 \text{ V}, V_{DD} = -5.0 \text{ V},$	t _r		15		
Turn-Off Delay Time	$I_D = -1.0 \text{ A}, \text{ R}_L = 5.0 \Omega,$ $R_G = 6.0 \Omega)$	t _{d(off)}		18		1
Fall Time		t _f		9		1
Total Gate Charge	$(V_{DS} = -16 \text{ V}, \text{ I}_{D} = -1.5 \text{ A}, V_{GS} = -4.5 \text{ V})$	QT		3.1		nC
SOURCE-DRAIN DIODE CHARAC	TERISTICS					
Continuous Current		۱ _S			-0.6	Α
Pulsed Current		I _{SM}			-0.75	
Forward Voltage (Note 2)	$(V_{GS} = 0 \text{ V}, \text{ I}_{S} = -0.6 \text{ A})$	V _{SD}			-1.0	V
Reverse Recovery Time	(I _S = -1.0 A, V _{GS} = 0 V, dI _S /dt = 100 A/µs)	t _{rr}		16		ns
		ta		11		
		t _b		5.5		
Reverse Recovery Stored Charge		Q _{RR}		8.5		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%. 2. Switching characteristics are independent of operating junction temperature.





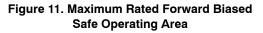


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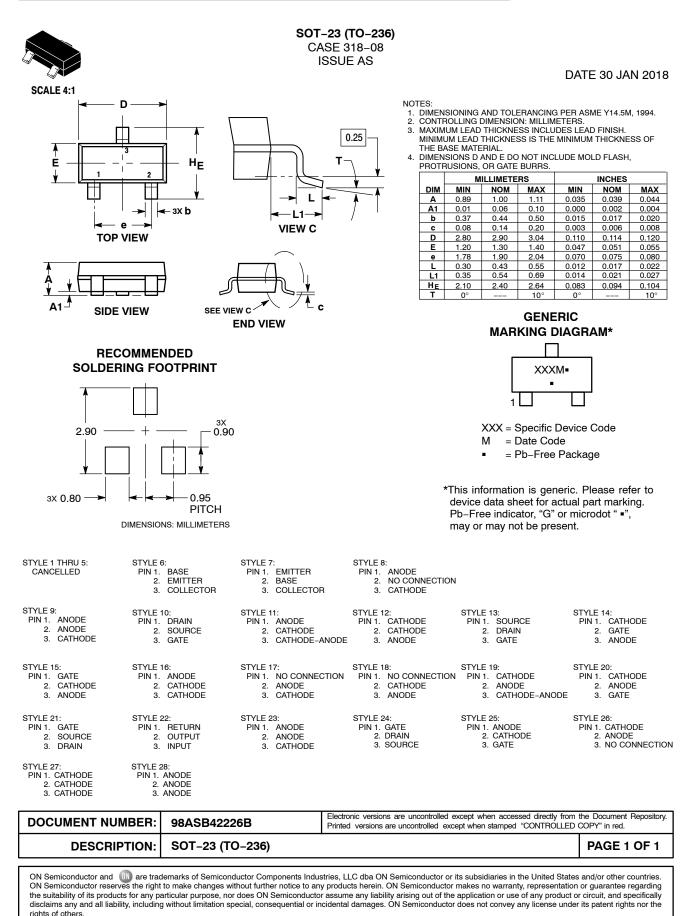
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